REV	DESCRIPTION			DATE	PREP	APPD
С	CO-28927			4/9/18	LT	DF/SM
С	CO-28927			4/9/18		DF/SM
	<b>Dicrosemi</b> Power Matters."	Oscillator S		<b>cation, H</b> For ard, LVPECI		VCXO
	MOUNT HOLLY SPRINGS, PA 17065	CODE IDENT NO	SIZE	DWG. NO.		REV
	IE RECORD OF APPROVAL FOR THIS MENT IS MAINTAINED ELECTRONICALLY WITHIN THE ERP SYSTEM	00136	Α		204898	С
	WITHIN THE ERP SYSTEM	UNSPECIFIED TOLE	RANCES	: N/A	SHE	ET 1 0F 20

- 1. SCOPE
- 1.1 General. This specification defines the design, assembly and functional evaluation of high reliability, hybrid voltage controlled oscillators produced by Microsemi. Devices delivered to this specification represent the standardized Parts, Materials and Processes (PMP) Program developed, implemented and certified for advanced applications and extended environments.
- 1.2 Applications Overview. The designs represented by these products were primarily developed for the MIL-Aerospace community. The lesser Design Pedigrees and Screening Options imbedded within DOC204898 bridge the gap between Space and COTS hardware by providing custom hardware with measures of mechanical, assembly and reliability assurance needed for Military or Ruggedized COTS environments.

### 2. APPLICABLE DOCUMENTS

2.1 Specifications and Standards. The following specifications and standards form a part of this document to the extent specified herein. The issue currently in effect on the date of quotation will be the product baseline, unless otherwise specified. In the event of conflict between the texts of any references cited herein, the text of this document shall take precedence.

<u>Military</u> MIL-PRF-55310 MIL-PRF-38534	Oscillators, Crystal Controlled, General Specification For Hybrid Microcircuits, General Specification For
Standards	
MIL-STD-202	Test Method Standard, Electronic and Electrical Component Parts
MIL-STD-750	Test Method Standard, Test Methods for Semiconductor Devices
MIL-STD-883	Test Methods and Procedures for Microelectronics
Other	
DOC204944	Test Specification, Hybrid VCXO, Hi-Rel Standard, LVPECL Output
QSP-90100	Quality Systems Manual, Microsemi
VL-65339	Identification Common Documents, Materials and Processes, Hi-Rel
	XO
DOC203982	DPA Specification
QSP-91502	Procedure for Electrostatic Discharge Precautions
-	2

#### 3. GENERAL REQUIREMENTS

3.1 Classification. All devices delivered to this specification are of hybrid technology conforming to Type 1, Class 2 of MIL-PRF-55310. Primarily developed as a Class S equivalent specification, options are imbedded within it to also produce Class B, Engineering Model and Ruggedized COTS devices. Devices carry a Class 2 ESDS classification per MIL-PRF-38534.

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3.2 Item Identification. Unique model number series are utilized to identify device package configurations as listed in Table 1.

3.3	Absolute Maximum Ratings.	
	a. Supply Voltage Range (V <sub>CC</sub> ):	0Vdc to +6.0Vdc
	b. Storage Temperature Range (T <sub>STG</sub> ):	-65°C to +125°C
	c. Junction Temperature (T <sub>J</sub> ):	+150°C
	d. Lead Temperature (soldering, 10 seconds):	+300°C

- 3.4 Design, Parts, Materials and Processes, Assembly, Inspection and Test.
- 3.4.1 Design. The ruggedized designs implemented for these devices are proven in military and space applications under extreme environments. Designs utilize 4-point crystal mounting in combination with Established Reliability (MIL-ER) components where possible. When specified, radiation hardening up to 50krad (Si) (RHA level L) is met by utilizing swept quartz and active device lots that have passed testing to that level.
- 3.4.1.1 Design and Configuration Stability. Barring changes to improve performance by reselecting passive chip component values to offset component tolerances, there will not be fundamental changes to the design or assembly or parts, materials and processes after first product delivery of that item without written approval from the procuring activity.
- 3.4.1.2 Environmental Integrity. Designs have passed the environmental qualification levels of MIL-PRF-55310. These designs have also passed extended dynamic levels of at least:
  - a. Sine Vibration: MIL-STD-202, Method 204, Condition G (30g pk.)
  - b. Random Vibration: MIL-STD-202, Method 214, Condition II-J (43.92g rms, three minute duration in each of three mutually perpendicular directions)
  - c. Mechanical Shock: MIL-STD-202, Method 213, Condition F (1500g, 0.5ms)
- 3.4.2 Prohibited Parts, Materials and Processes. The items listed are prohibited for use in high reliability devices produced to this specification.
  - a. Gold metallization of package elements without a barrier metal.
  - b. Zinc chromate as a finish.
  - c. Cadmium, zinc, or pure tin external or internal to the device.
  - d. Plastic encapsulated semiconductor devices.
  - e. Ultrasonically cleaned electronic parts.
  - f. Heterojunction Bipolar Transistor (HBT) technology.
  - g. 'getter' materials
- 3.4.3 Assembly. Manufacturing utilizes standardized procedures, processes and verification methods to produce MIL-PRF-55310 Class S / MIL-PRF-38534 Class K equivalent devices. MIL-PRF-38534 Group B Option 1 in-line inspection is included on radiation hardened part numbers to further verify lot pedigree. Traceability of all components and production lots are in accordance with MIL-PRF-38534, as a minimum. Tabulated records are provided as a part of the deliverable data package. Devices are handled in accordance with Microsemi document QSP-91502 (Procedure for Electrostatic Discharge Precautions).

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- 3.4.4 Inspection. The inspection requirements of MIL-PRF-55310 apply to all devices delivered to this document. Inspection conditions and standards are documented in accordance with the Quality Assurance, ISO-9001 and AS9100 derived, System of QSP-90100.
- 3.4.5 Test. The Screening test matrix of Table 5 is tailored for selectable-combination testing to eliminate costs associated with the development/maintenance of device-specific documentation packages while maintaining performance integrity.
- 3.4.6 Marking. Device marking shall be in accordance with the requirements of MIL-PRF-55310.
- 3.4.7 Ruggedized COTS Design Implementation. Design Pedigree "D" devices (see ¶ 5.2) use the same robust designs found in the other device pedigrees. They do not include the provisions of traceability or the Class-qualified components noted in paragraphs 3.4.3 and 4.1.
- 4. DETAIL REQUIREMENTS
- 4.1 Components
- 4.1.1 Crystals. Cultured quartz crystal resonators are used to provide the selected frequency for the devices. The optional use of Premium Q swept quartz can, because of its processing to remove impurities, be specified to minimize frequency drift when operating in radiation environments. In accordance with MIL-PRF-55310, the manufacturer has a documented crystal element evaluation program.
- 4.1.2 Passive Components. Passive components will have the same pedigree as the die specified in paragraph 7.1. When required, established Reliability (ER) failure level R minimum passive components are procured from QPL suppliers where possible. Lot evaluations are in accordance with MIL-PRF-38534 or Enhanced Element Evaluation as specified in Table 8. When used, inductors may be open construction and may use up to 47 gauge wire.
- 4.1.3 Class S Active Devices. Active Devices are procured from wafer lots that have passed MIL-PRF-38534 Lot Acceptance Tests for Class S devices. When optionally specified, further testing in accordance with MIL-PRF-55310 and MIL-PRF-38534 is performed for radiation hardness assurance (excluding varactor diodes) and for Enhanced Element Evaluation as specified in Tables 6 and 7. Those active devices, identified by a unique part number, are certified for 50krad (Si) ELDRS. Varactor diodes are considered radiation tolerant by design.
- 4.1.3.1 Class B Active Devices. When specified, active devices assembled into DOC204898 design pedigree letters "B" and "C" devices (¶ 5.2a) are procured from wafer lots that have passed MIL-PRF-55310 element evaluations for Class B devices.
- 4.1.4 Packages. Packages are procured that meet the construction, lead materials and finishes as specified in MIL-PRF-55310. All leads are Kovar with gold plating over a nickel underplate. Package lots are upscreened in accordance with the requirements of MIL-PRF-38534 as applicable.

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- 4.1.5 Traceability and Homogeneity. All design pedigrees except option D have active device lots that are traceable to the manufacturer's individual wafer; all other elements and passive components are traceable to their manufacturer and incoming inspection lots. Design pedigrees E, R, V and X have homogenous material. In addition, swept quartz crystals are traceable to the quartz bar and the processing details of the autoclave lot, as applicable.
- 4.1.6 Enhanced Element Evaluation. When Design Pedigree Option "E" is specified, active and passive devices with Enhanced Element Evaluation as listed in Table 6, 7 and 8 shall be implemented for the highest reliability preference.
- 4.2 Mechanical.
- 4.2.1 Package Outline. Table 1 links each Hi-Rel Standard Model Number of this specification to a corresponding package style. Mechanical Outline information of each package style is found in the referenced Figure.
- 4.2.2 Thermal Characteristics. The worst case thermal characteristics of each package style and active device are found in Table 4.
- 4.3 Electrical.
- 4.3.1 Input Power. Devices are designed for standard +3.3 volt dc operation, ±5%. Current is measured, no load, at maximum rated operating Voltage.
- 4.3.2 Temperature Range. Operating range is -40°C to +85°C.
- 4.3.3 Absolute Pull Range. Absolute pull range is defined as the minimum guaranteed amount the VCXO can be varied, about the center frequency (fo). It accounts for degradations including temperature stability (-40 to 85°C), aging (15 years), radiation effects, power supply variations (±5%) and load variations (±10%).
- 4.3.4 Frequency Aging. When tested in accordance with MIL-O-55310 Group B inspection, the 15-year aging projection shall not cause the minimum APR limit to be exceeded.
- 4.3.5 Operating Characteristics. Symmetrical square wave limits are dependent on the device frequency and are in accordance with Table 2 and Figure 1. Start-up time is 10.0 msec. maximum.
- 4.3.6 Output Load.  $50\Omega$  to Vcc-2.0V (each output)

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### 5. QUALITY ASSURANCE PROVISIONS AND VERIFICATION

- 5.1 Verification and Test. Device lots shall be tested prior to delivery in accordance with the applicable Screening Option letter as stated by the 15<sup>th</sup> character of the part number. Table 5 tests are conducted in the order shown and annotated on the appropriate process travelers and data sheets of the governing test procedure. For devices that require Screening Options that include MIL-PRF-55310 Group A testing, the Post-Burn-In Electrical Test and the Group A Electrical Test are combined into one operation.
- 5.1.1 Screening Options. The Screening Options, by letter, are summarized as:
  - A Modified MIL-PRF-38534 Class K
  - B Modified MIL-PRF-55310 Class B Screening & Group A Quality Conformance Inspection (QCI)
  - C Modified MIL-PRF-55310 Class S Screening & Group A QCI
  - D Modified MIL-PRF-38534 Class K with Group B Aging
  - E Modified MIL-PRF-55310 Class B Screening, Groups A & B QCI
  - F Modified MIL-PRF-55310 Class S Screening, Groups A & B QCI
  - G Modified MIL-PRF-55310 Class B Screening & Post Burn-in Nominal Electricals
  - X Engineering Model (EM)
- 5.2 Optional Design, Test and Data Parameters. The following is a list of design, assembly, inspection and test options that can be selected or added by purchase order request.
  - a. Design Pedigree (choose one as the 5<sup>th</sup> character in the part number):
    - (E) Enhanced Element Evaluation, 50krad Class S die, Premium Q Swept Quartz
    - (R) Hi-Rel design w/ 50krad Class S die, Premium Q Swept Quartz
    - (V) Hi-Rel design w/ 50krad Class S die, Non-Swept Quartz
    - (X) Hi-Rel design w/ Non-Swept Quartz, Class S die
    - (B) Hi-Rel design w/ Swept Quartz, Class B die
    - (C) Hi-Rel design w/ Non-Swept Quartz, Class B die
    - (D) Hi-Rel design w/ Non-Swept Quartz and commercial grade components
  - b. Input Voltage, (B) for 3.3V as the 14<sup>th</sup> character
  - c. Frequency-Temperature Slew Test
  - d. Radiographic Inspection
  - e. Group C Inspection: MIL-PRF-55310 (requires 8 destruct specimens)
  - f. Group C Inspection: MIL-PRF-38534, Table C-Xc, Condition PI [requires 8 destruct specimens Life (5), RGA (3)]. Subgroup 1 fine leak test to be performed per MIL-STD-202, Method 112, Condition C.
  - g. Internal Water-Vapor Content (RGA) samples and test performance
  - h. MTBF Reliability Calculations
  - i. Worst Case/Derating Analysis (MIL-HDBK-1547) with Tj Max =  $+105^{\circ}$ C; Derated Maximum Operating Temp = Tj Max -  $\Delta$ Tj
  - j. Deliverable Process Identification Documentation (PID)
  - k. Customer Source Inspection (pre-cap / final)

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- 1. Destruct Physical Analysis (DPA): MIL-STD-1580 with exceptions as specified in Microsemi DOC203982.
- m. Qualification: In accordance with MIL-PRF-55310, Table IV (requires 11 destruct specimens).
- n. Qualification: In accordance with EEE-INST-002, Section C4, Table 3, Level 1 or 2 (requires 11 destruct specimens)
- o. High Resolution Digital Pre-Cap Photographs (20 Megapixels minimum)
- p. Hot solder dip of leads with Sn63/Pb37 solder prior to shipping.
- 5.2.1 NASA EEE-INST-002. A combination of Design Pedigree E or R, Option F Screening, Group C Inspection in accordance with Table VII of MIL-PRF-55310 and RGA, meet the requirements of Level 1 device reliability. A combination of Design Pedigree B, Option E Screening, Radiographic Inspection, Group C Inspection in accordance with Table VII of MIL-PRF-55310 and RGA, meet the requirements of Level 2 device reliability.
- 5.3 Test Conditions. Unless otherwise stated herein, inspections are performed in accordance with those specified in MIL-PRF-55310 and MIL-PRF-38534, in that order. Process travelers identify the applicable methods, conditions and procedures to be used. Examples of electrical test procedures that correspond to MIL-PRF-55310 requirements are shown in Table 3.
- 5.4 Special Tests and Descriptions.
- 5.4.1 Frequency-Temperature Slew. Frequency-Temperature Slew Test has been developed as an indicator of higher than normal internal water vapor content. The incremental temperature sweep from +85°C to -40°C and back to +85°C records output frequency fluctuations emulating the mass loading of moisture deposited on the crystal blank surface. Though not replacing a customer's internal water-vapor content (RGA) requirement, confidence is increased without destructively testing otherwise good devices.
- 5.5 Deliverable Data. The manufacturer supplies the following data, as a minimum, with each lot of devices:
  - a. Completed assembly and screening lot travelers, including rework history and Certificate of Conformance.
  - b. Electrical test variables data, identified by unique serial number.
  - c. Frequency-Temperature Slew plots, Radiographic films, Group C data and RGA data as required by purchase order.
  - d. Traceability, component LAT, enclosure LAT and RLAT (if specifically requested on the purchase order).
- 5.6 Discrepant Material. All MRB authority resides with the procuring activity.
- 5.7 Failure Analysis. Any catastrophic failure (no clocking, no current) at Post Burn-In or after will be evaluated for root cause. The customer will be notified after occurrence and upon completion of the evaluation.

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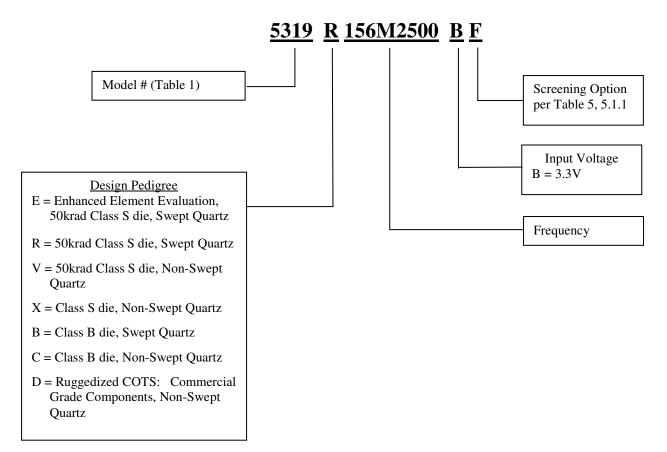
#### 6. PREPARATION FOR DELIVERY

6.1 Packaging. Devices will be packaged in a manner that prevents handling and transit damage during shipping. Devices will be handled in accordance with MIL-STD-1686 for Class 1 devices.

#### 7. ORDERING INFORMATION

7.1 Ordering Part Number. The ordering part number is made up of an alphanumeric series of 15 characters. Design-affected product options, identified by the parenthetic letter on the Optional Parameters list (¶ 5.2a and b), are included within the device part number.

The Part Number breakdown is described as:



7.1.1 Model Number. The device model number is the four (4) digit number assigned to a corresponding package and output combination per Table 1.

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- 7.1.2 Design Pedigree. Class S variants correspond to either letter "E", "R", "V" or "X" and are described in paragraph 5.2a. Class B variants correspond to either letter "B" or "C" and are described in paragraph 5.2a. Ruggedized COTS, using commercial grade components, corresponds to letter "D".
- 7.1.3 Output Frequency. The nominal output frequency is expressed in the format as specified in MIL-PRF-55310 utilizing eight (8) characters.
- 7.1.4 Input Voltage. Voltage is the 14<sup>th</sup> character, letter "B" represents +3.3V.
- 7.1.5 Screening Options. The 15<sup>th</sup> character is the Screening Option (letter A thru G or X) selected from Table 5.
- 7.2 Optional Design, Test and Data Parameters. Test and documentation requirements above that of the standard high reliability model shall be specified by separate purchase order line items (as listed in ¶ 5.2c thru n).

HI-REL				PIN I	'O <u>1</u> /		MECHANICAL
STANDARD	PACKAGE	Vcc	Vc	Q	Qnot	Gnd/Case	OUTLINE
MODEL #							
5319	16 Lead Flatpack	16	1	9	10	8, 11	FIGURE 2 or 4
5321	16 Lead Flatpack	16	1	9	10	8, 11	FIGURE 3 or 5

 $\underline{1}$ /. All unassigned pins have no internal connections or ties.

2/. Center frequencies greater than 320 MHz use mechanical outlines Figure 4 or 5.

**TABLE 1** - Item Identification and Package Outline

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Frequency Rang	e @ 3.3V Operation	on: 100 MHz to	700 MHz <u>1</u> /				
Temperature Range: -40°C to +85°C							
Absolute Pull Ra	ange: ±20 ppm mi	n.					
Control Voltage	(Vc) Range: 0.0V	to +3.3V					
Slope: Positive							
Linearity: ±10%	max.						
F vs. V Gain: 55	ppm/V typical						
Sub-Harmonics:	-30 dBc max.						
Frequency-Volta	age Tolerance: ±4	ppm max. (Vcc	±5%)				
Frequency Aging	g: 15 year project	ion based on 30	day test included	in APR calculation			
Start-up Time: 1	10.0 ms max.						
Output Voltage:	$V_{OH} = Vcc - 1.085$ t	to Vcc-0.880, V	$_{OL}$ =Vcc-1.830 to V	/cc-1.555			
Frequency	Current,	Rise / Fall	Duty Cycle	BW Jitter,			
Range	No load	Time	(%)	12kHz-20MHz			
(MHz)	(mA max)	(ps max.)		(ps rms max)			
100 - 200	65	900	40 to 60	0.75			
>200 - 320	65	600	40 to 60	0.5			
>320 - 700	75	400	40 to 60	0.5			

<u>1</u>/. Waveform measurement points and logic limits are in accordance with Figure 1.

OPERATION LISTING	REQUIREMENTS AND
	CONDITIONS 1/
@ all Ele	ctrical tests
Input Current (no load)	MIL-PRF-55310, Para 4.8.5.1
Initial Accuracy @ Ref. Temp.	MIL-PRF-55310, Para 4.8.6
Output Logic Voltage Levels	MIL-PRF-55310, Para 4.8.21.3
Rise and Fall Times	MIL-PRF-55310, Para 4.8.22
Duty Cycle	MIL-PRF-55310, Para 4.8.23
Frequency Deviation	MIL-PRF-55310, Para 4.8.31.1
Linearity	MIL-PRF-55310, Para 4.8.31.5
@ Post Burn-I	n Electrical only
Overvoltage Survivability	MIL-PRF-55310, Para 4.8.4
Initial Freq. – Temp. Accuracy	MIL-PRF-55310, Para 4.8.10.1
Freq. – Voltage Tolerance	MIL-PRF-55310, Para 4.8.14
Start-up Time (fast/slow start)	MIL-PRF-55310, Para 4.8.29

1/. Waveform measurement points and logic limits are in accordance with Figure 1.

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	Model #	Thermal Resistance Junction to Case $\theta_{ic}$ (°C / W)	$\Delta$ Junction Temp. T <sub>j</sub> (°C @ max. power)	Typical Weight (Grams)
ſ	5319/5321	39	5.3	7.5

<u>Note</u>. These oscillators contain multiple active devices. This calculation shows the worst case  $\theta_{jc}$  and temperature rise of those devices.

**TABLE 4 -** Typical Thermal Characteristics and Weight

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OPN.	OPERATION LISTING	REQUIREMENTS AND CONDITIONS	Option	Option						
NO.			А	В	С	D	E	F	G	Х
	SCREENING	MIL Class Similarity	K	B-	S-	K+	В	S		EM
			100%	100%	100%	100%	100%	100%	100%	100%
1	Non-Destruct Bond Pull	MIL-STD-883, Meth 2023	Х	NR	X	Х	NR	X	NR	NR
2	Internal Visual	MIL-STD-883, Meth 2017 Class K, Meth 2032 Class K	Х	Х	X	Х	X	X	X	Х
3	Stabilization (Vacuum) Bake	MIL-STD-883, Meth 1008, Cond C, 150°C	Х	Х	X	Х	Х	X	Х	Х
			48 hrs.	24 hrs.	48 hrs.	48 hrs.	24 hrs.	48 hrs.	24 hrs.	24 hrs.
4	Thermal Shock	MIL-STD-883, Meth 1011, Cond A	NR	NR	Х	NR	NR	Х	NR	NR
5	Temperature Cycle	MIL-STD-883, Meth 1010, Cond. B, 10 cycles min.	Х	Х	Х	Х	Х	Х	Х	NR
6	Constant Acceleration	MIL-STD-883, Meth 2001, Cond A, Y1 plane only, 5000 g's	Х	Х	X	Х	X	X	X	NR
7	Particle Impact Noise Detection	MIL-STD-883, Meth 2020, Cond B	Х	Х	Х	Х	Х	Х	NR	Х
8	Electrical Testing, Pre Burn-In	Perform tests in Table 3. Nominal Vcc, nominal temperature	Х	Х	Х	Х	Х	Х	Х	Х
9	1 <sup>st</sup> Burn-In	MIL-STD-883, Meth 1015, Condition B	X 160 hrs.	X 160 hrs.	X 240 hrs.	X 160 hrs.	X 160 hrs.	X 240 hrs.	X 160 hrs.	NR
10	Electrical Testing, Intermediate	Perform tests in Table 3. Nominal Vcc, nominal temperature	Х	NR	NR	Х	NR	NR	NR	NR
11	2 <sup>nd</sup> Burn-In	MIL-STD-883, Meth 1015, Condition B	X 160 hrs.	NR	NR	X 160 hrs.	NR	NR	NR	NR
12	Freq-Temp Slew Test	Operating temp. range, frequency plotted at 1.0°C steps	AR	AR	AR	AR	AR	AR	NR	NR
13	Electrical Testing, Post Burn-In (Group A)	Perform tests in Table 3. Nominal Vcc & extremes, nominal temperature & extremes	Х	Х	Х	Х	Х	Х	X nom. Vcc	NR
14	Seal: Fine Leak	MIL-STD-202, Meth 112, Cond C 5 x 10 <sup>8</sup> atm cc/sec max	Х	Х	Х	Х	X	Х	X	Х
15	Seal: Gross Leak	MIL-STD-202, Meth 112, Cond D	Х	Х	Х	Х	Х	Х	Х	Х
16	Radiographic Inspection	MIL-STD-883, Meth 2012	Х	AR	AR	Х	AR	Х	NR	NR
17	Solderability	MIL-STD-883, Meth 2003	1/	1/	1/	1/	1/	1/	1/	NR
18	External Visual & Mechanical	MIL-STD-883, Meth 2009	X 2/	X 2/	X 2/	X 2/	X <u>2</u> /	X <u>2</u> /	X 2/	X <u>2</u> /
19	Aging, 30 Day <u>3/</u> (M55310 Group B)	MIL-PRF-55310, para. 4.8.35.1	NR	NR	NR	X	13 pcs.	X	NR	NR

LEGEND: X = Required, NR = Not Required, AR = As Required

#### **TABLE 5** - Test Matrix

<u>1</u>/ Performed at package LAT. Include LAT data sheet

 $\frac{1}{2}$  / When specified, RGA samples will be removed from the lot after completion of this operation. Use of Screening failures require customer concurrence.  $\frac{3}{2}$ / By customer request, the Aging test may be terminated after 15 days if the measured aging rate is less than one-half the specified aging rate, as described in paragraph 4.3.4.1 herein. See the customer PO.

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Subgroup	Class	Test	Mil-STD-883		Quantity	Mil-PRF- 38534 Reference
	K	-	Method	Condition	(accept number)	Paragraph
1	X	Element Electrical A. May perform at wafer level B. All failures shall be removed from the lot C. Perform at room ambient			100%	C.3.3.1
2	Х	Element Visual	2010		100%	C.3.3.2
3	X	Internal Visual	2010		10(0) or 22(0)	C.3.3.3 C.3.3.4.2
4	Х	Temperature Cycling	1010	С		C.3.3.3
	Х	Mechanical Shock	2002	B, Y1	10(0)	
		or Constant Acceleration	2001	direction 3,000 G, Y1 direction	22(0)	
	Х	Interim Electrical				C.3.3.4.3
	X	Burn-In	1015	240 hours minimum at +125°C		
	Х	Post Burn-In Electrical				C.3.3.4.3
	Х	Steady State Life	1005			
	Х	Final Electrical				C.3.3.4.3
5	X	Wire Bond Evaluation	2011		10(0) wires or 20(1) wires	C.3.3.3 C.3.3.5
6	Х	SEM	2018		See method 2018	C.3.3.6

#### Notes:

Subgroups 3, 4, & 5 shall be performed on a sample of 10 die if the wafer lot is from a QPL/QML line. If the die are from commercial wafer lots, then the sample size shall be 22 die.

## **TABLE 6 - MICROCIRCUIT ENHANCED ELEMENT EVALUATION**

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Α	00136	-@-E-]	N/A	DOC204898	С	13

Subgroup	Class	Test	Mil-ST	D-750	Quantity	Mil-PRF- 38534 Reference
	K		Method	Condition	(accept number)	Paragraph
1	X	Element Electrical A. May perform at wafer level B. All failures shall be removed from the lot		Perform at room ambient	100%	C.3.3.1
2	Х	Element Visual	2069, 2070, 2072, 2073		100%	C.3.3.2
3	X	Internal Visual	2069, 2070, 2072, 2073, 2074		10(0) or 22(0) (Notes 1 & 2)	C.3.3.3 C.3.3.4.2
4	X	Temperature Cycling	1051	С		C.3.3.3
	Х	Surge Current (when applicable)	4066	A or B as specified		
	X	Constant Acceleration	2006 2001	Y1 direction 20,000 G / 10,000 G for Pd ≥ 10W	10(0) 22(0) (See Notes 1 & 2)	
	Х	Interim Electrical				C.3.3.4.3
	X	High Temperature Reverse Bias (HTRB)	1039 1042 1038	A B A		
	x	Interim Electrical & Delta		Complete Within 16 hrs of HTRB completion		
	X	Burn-In 240 hours	1039, 1042 1038 1040	B A B		
	Х	Post Burn-In Electrical				C.3.3.4.3
	X	Steady State Life 1000 hours	1026 1037 1042 1048			
	X	Final Electrical				C.3.3.4.3
5	X	Wire Bond Evaluation	2011		10(0) wires or 20(1) wires	C.3.3.3 C.3.3.5
6	X	SEM	2018 2077		See method 2018 or 2077 & Note 2	C.3.3.6

## **TABLE 7: SEMICONDUCTOR ENHANCED ELEMENT EVALUATION**

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136		N/A	DOC204898	С	14

Part Type	Test	Requirements Paragraph	Sample Size	Allowable Rejects
Ceramic capacitors (Produc	tion lot definition shall be pe	r M55681 or M123 for	chips, or M49470 T-lev	el for stacks)
M55681 FRL S or M123 (chips)	N/A	N/A	N/A	N/A
DSCC Dwg COTS (chips)	Ultrasonic scan or CSAM	M123	100%	N/A
	Group A	M123	M123	M123
	Group B, Subgroups 1 & 2	M123	M123	M123
T-level M49470 (stacked)	N/A	N/A	N/A	N/A
General purpose M49470,	Ultrasonic scan or CSAM	M49470 for T-level	100%	N/A
DSCC dwg or COTS	Group A	M49470 for T-level	M49470 for T-level	M49470 for T-level
(stacked)	Group B, Subgroups 2, 4 & 5b	M49470 for T-level	M49470 for T-level	M49470 for T-level
Tantalum Chip Capacitors minimum Weibull C and surg	ge current option C. Production			up A in M55365 with
M55365	Group A (Weibull C minimum with surge current option C)	M55365	M55365	M55365
DSCC Dwg, COTS	Group A (Weibull C minimum with surge current option C)	M55365	M55365	M55365
	Group B	M55365	M55365	M55365
<b>Resistor Chips</b> (Note: Gluin without extensive design/proper M55342).				
M55342 FRL R or S	N/A	N/A	N/A	N/A
DSCC Dwg, COTS	Group A	M55342 for T-level	M55342 for T-level	M55342 for T-level
	Group B	M55342 for T-level	M55342 for T-level	M55342 for T-level
Inductors (See Paragraph	4.1.2)			
Magnetics, Closed Construct qualified and the effects of th cycling plus electrical measur shall conform to MIL-STD-9	e long term performance of t rements as specified in Group 81 requirements).	he hybrids verified. Wl p A of Mil-Std-981. De	hen stacking magnetics, sign, workmanship and	a repeat of the thermal materials/processes
Magnetics, Open Construction magnetic core. These parts measurements and visual insp	are fully visually inspectable			
	a			
Custom closed magnetics	Group A	Mil-STD-981	Mil-STD-981	Mil-STD-981

# TABLE 8: PASSIVE COMPONENT ENHANCED ELEMENT EVALUATION

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC204898	С	15

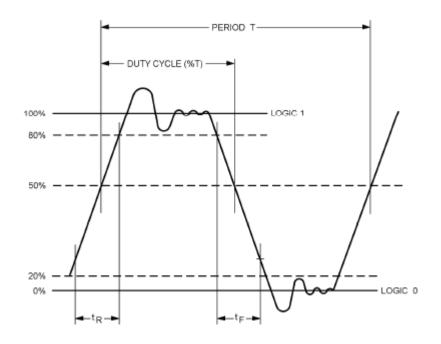


FIGURE 1 Differential Output Waveform

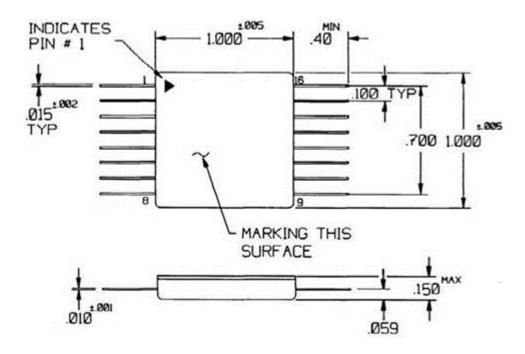
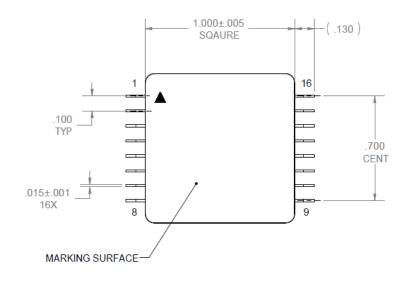


FIGURE 2 Model 5319 Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC204898	С	16



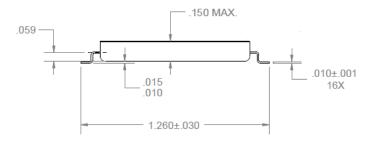


FIGURE 3 Model 5321 Package Outline

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC204898	С	17

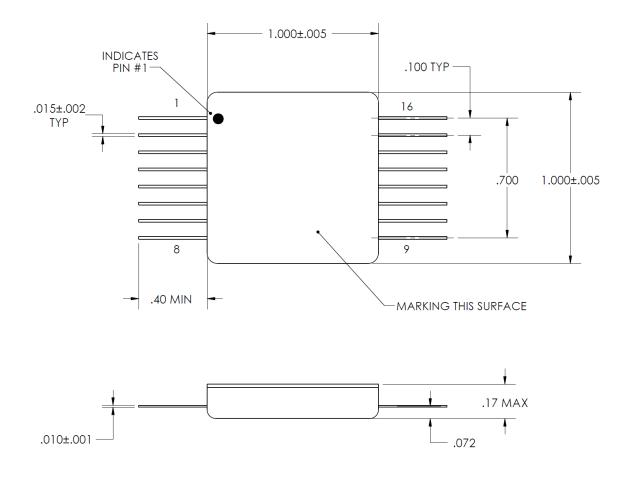


FIGURE 4 Model 5319 Package Outline (Center Frequency >320 MHz)

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-]	N/A	DOC204898	С	18

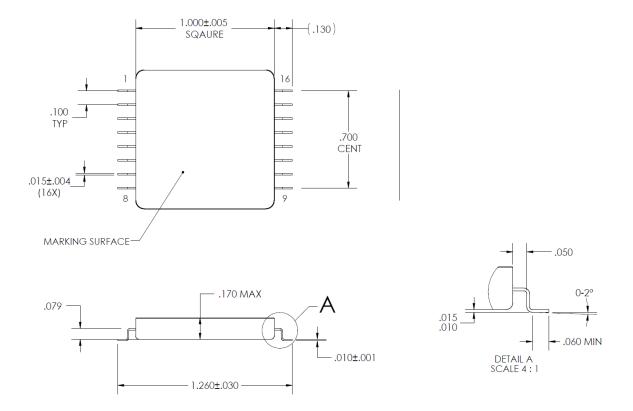
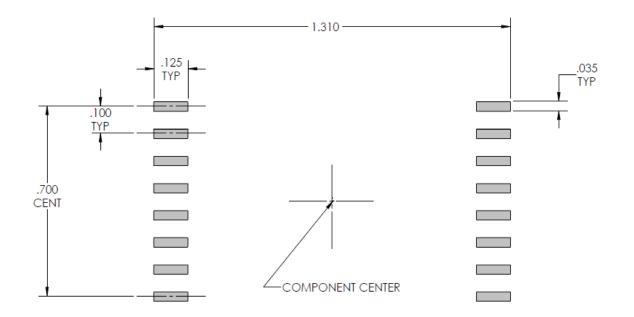


FIGURE 5 Model 5321 Package Outline (Center Frequency >320 MHz)

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC204898	С	19

APPENDIX A Recommended Land Pattern



Model 5321

SIZE	CODE IDENT NO.	THIRD ANGLE PROJECTION	UNSPECIFIED TOLERANCES	DWG NO.	REV.	SHEET
Α	00136	-@-E-J	N/A	DOC204898	С	20